ASSP

Serial Input PLL Frequency Synthesizer

MB1511

■ DESCRIPTION

The Fujitsu MB1511 is a single chip serial input PLL frequency synthesizer designed for VHF tuner and cellular telephone applications.

It contains a 1.1 GHz dual modulus prescaler which enables pulse swallow function, and an analog switch to speed up lock up time.

It operates supply voltage of 3.0 V typ. and dissipates 7 mA typ. of current realized through the use of Fujitsu's unique U-ESBIC Bi-CMOS technology.

The MB1511 is housed in SSOP package, this enables high integration.

■ FEATURES

- Low power supply voltage: Vcc = 2.7 to 5.5 V
- High operating frequency: fin MAX = 1.1 GHz (VIN MIN = −10dBm)
- Pulse swallow function: 64/65 or 128/129
- Low supply current: Icc = 7 mA typ.

Serial input 18-bit programmable divider consisting of:

Binary 7-bit swallow counter: 0 to 127

Binary 11-bit programmable counter: 16 to 2047

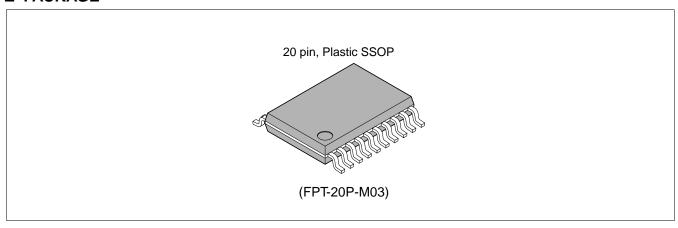
• Serial input 15-bit programmable reference divider consisting of:

Binary 14-bit programmable reference counter: 8 to 16383

1-bit switch counter (SW) sets divide ratio of prescaler

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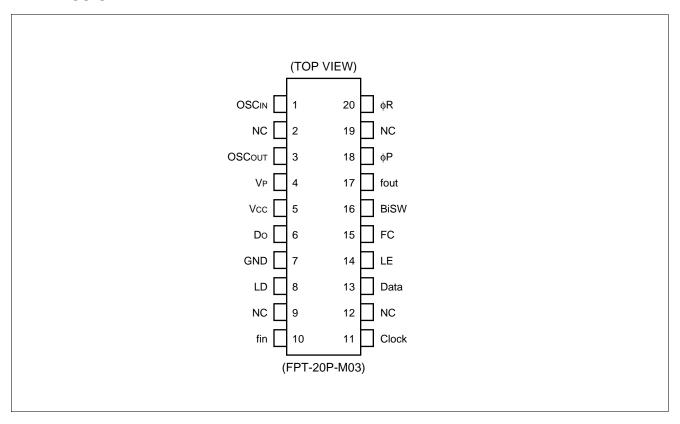
■ PACKAGE



(Continued)

- On-chip analog switch achieves fast lock up time
- 2 types of phase detector output On-chip charge pump (Bipolar type) Output for external charge pump
- Wide operating temperature: -40°C to +85°C
- 20-pin Plastic Shrink Small Outline Package (Suffix: -PFV)

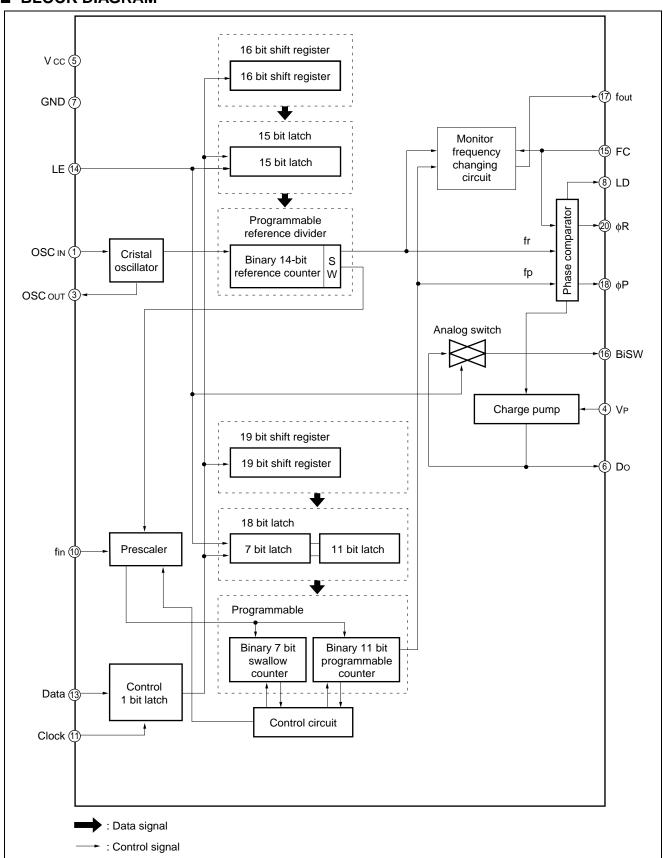
■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Pin Name	I/O	Functions		
1	OSCIN	I	Oscillator input.		
3	OSCout	0	Oscillator oùtput. A crystal is placed between OSC _{IN} and OSC _{OUT} .		
4	VP	_	Power supply input for charge pump and analog switch.		
5	Vcc	_	Power supply voltage input.		
6	Do	0	Charge pump output. The characteristics of charge pump is reversed depending upon FC input.		
7	GND	_	Ground.		
8	LD	0	Phase comparator output. Normally this pin outputs high level. While the phase difference of fr and fp exists, this pin outputs low level.		
10	fin	I	Prescaler input. The connection with an external VCO should be AC connection.		
11	Clock	I	Clock input for 19-bit shift register and 16-bit shift register. On rising edge of the clock shifts one bit of data into the shift registers.		
13	Data	I	Binary serial data input. The last bit of the data is a control bit which specified destination of shift registers. When this bit is high level and LE is high level, the data stored in shift register is transferred to 15-bit latch. When this bit is low level and LE is high level, the data is transferred to 18-bit latch.		
14	LE	I	Load enable input (with internal pull up resistor). When LE is high or open, the data stored in shift register is transferred into latch depending upon the control bit. At the time, internal charge pump output is connected to BiSW pin because internal analog switch becomes ON state.		
15	FC	I	Phase select input of phase comparator (with internal pull up resistor). When FC is low level, the characteristics of charge pump, phase comparator is reversed. FC input signal controls fout pin (test pin) output level, fr or fp.		
16	BiSW	0	Analog switch output. Usually BiSW pin is set high-impedance state. When internal analog switch is ON (LE pin is high level), this pin outputs internal charge pump output.		
17	fout	0	Minitor pin of phase comparator input. fout pin outputs either programmable reference divider output (fr) or programmable divider output (fp) depending upon FC pin input level. FC = H: It is the same as fr output level. FC = L: It is the same as fp output level.		
18	φР	0	Output for external charge pump.		
20	φR	0	The characteristics are reversed according to FC input.		
2, 9 12, 19	NC	_	No connection.		

■ BLOCK DIAGRAM



■ FUNCTIONAL DESCRIPTIONS

1. Pulse Swallow Function

The divide ratio is set using the following equation.

 $\mathsf{fvco} = [(\mathsf{M} \times \mathsf{N}) + \mathsf{A}] \times \mathsf{fosc} \div \mathsf{R}$

fvco: Output frequency of external voltage controlled oscillator (VCO) M: Preset modulus of external dual modulus prescaler (64 or 128)

N : Preset divide ratio of binary 11-bit programmable counter (16 to 2047) A : Preset divide ratio of binary 7-bit swallow counter ($0 \le A \le 127$, A < N)

fosc : Output frequency of the external reference frequency oscillator

R: Preset divide ratio of binary 14-bit programmable reference counter (8 to 16383)

2. Serial Data Input

Serial data input is achieved by three inputs, such as Data pin, Clock pin and LE pin. Serial data input controls 15-bit programmable reference divider and 18-bit programmable divider, respectively.

Binary serial data is input to Data pin.

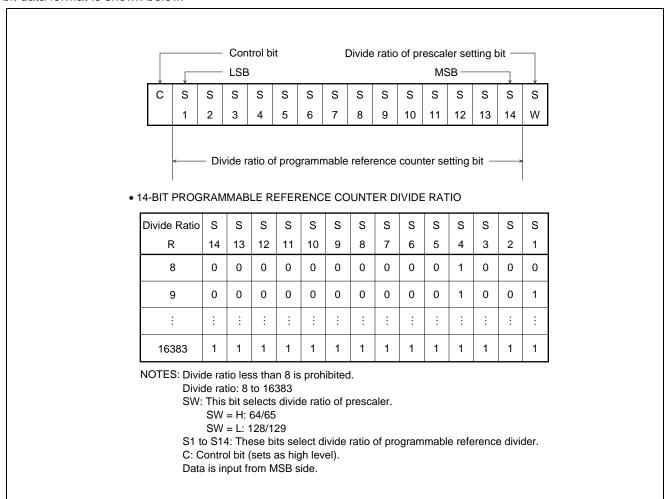
On rising edge of clock shifts one bit of serial data into the internal shift registers and when load enable pin is high level or open, stored data is transferred into latch depending upon the control bit.

Control data "H" data is transferred into 15-bit latch.

Control data "L" data is transferred into 18-bit latch.

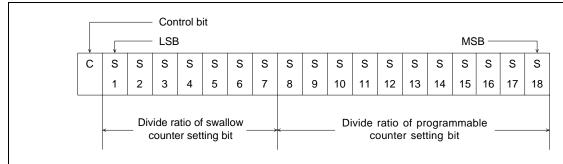
(1) Programmable Reference Divider

Programmable reference divider consists of 16-bit shift register, 15-bit latch and 14-bit reference counter. Serial 16-bit data format is shown below.



(2) Programmable Divider

Programmable divider consists of 19-bit shift register, 18-bit latch, 7-bit swallow counter and 11-bit programmable counter. Serial 19-bit data format is shown following page.



• 7-bit Swallow Counter Divide Ratio

Divide Ratio	S	s	s	S	s	s	S
А	7	6	5	4	3	2	1
0	0	0	0	0	0	0	0
1	0	0	0	0	0	0	1
:	÷	÷	÷	÷	÷	÷	:
127	1	1	1	1	1	1	1

Note: Divide ratio: 0 to 127

• 11-bit Programmable Counter Divide Ratio

Divide Ratio	S	s	s	s	s	s	s	s	s	S	S
N	18	17	16	15	14	13	12	11	10	9	8
16	0	0	0	0	0	0	1	0	0	0	1
17	0	0	0	0	0	0	1	0	0	0	1
:	:	÷	÷	÷	÷	÷	÷	÷	÷	:	:
2047	1	1	1	1	1	1	1	1	1	1	1

Notes: Divide ratio less than 16 is prohibited.

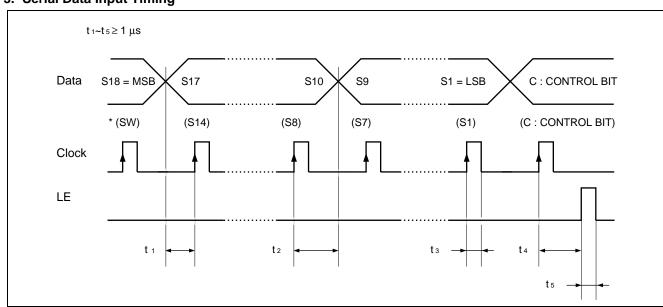
Divide ratio: 16 to 2047

S1 to S7: Swallow counter divide ratio setting bit. (0 to 127)

S8 to S18: Programmable counter divide ratio setting bit. (16 to 2047)

C: Control bit (sets as low level). Data is input from MSB side.

3. Serial Data Input Timing



^{* :} Paranthesis data is used for setting divide ratio of programmable reference divider. On rising edge of clock shifts one bit of data in the shift register.

4. Phase Characteristics

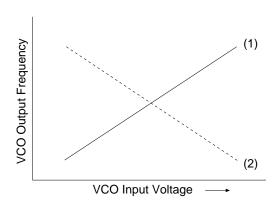
FC pin is provided to change phase characteristics of phase comparator. Characteristics of internal charge pump output level (Do), phase comparator output level (ϕR , ϕP) are reversed depending upon FC pin input level. Also, monitor pin (fout) output level of phase comparator is controlled by FC pin input level. The relation between outputs (Do, ϕR , ϕP) and FC input level are shown below.

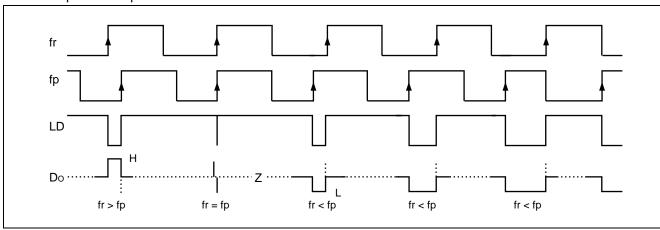
		FC : "H"	or open		FC : "L"			
	Do	φR	φР	fout	Do	φR	φР	fout
fr > fp	Н	L	L	(fr)	L	Н	Z	(fp)
fr = fp	Z	L	Z	(fr)	Z	L	Z	(fp)
fr < fp	L	Н	Z	(fr)	Н	L	L	(fp)

Note: Z = (High impedance)

Depending upon VCO characteristics, FC pin should be set accordingly:

 When VCO characteristics are like (1), FC should be set High or open circuit; When VCO characteristics are like (2), FC should be set Low.





Phase comparator output waveforms are shown below.

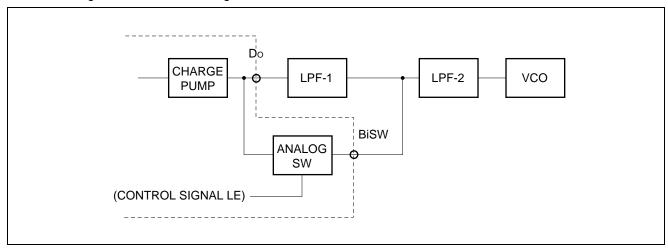
Notes: Phase difference detection range: -2π to $+2 \pi$ Spike appearance depends on charge pump characteristics. Also, the spike is output in order to diminish dead band. When fr>fp or fr<fp, spike might not appear depending upon charge rump characteristics.

5. Analog Switch

ON/OFF of analog switch is controlled by LE input signal. When the analog switch is ON, internal charge pump output (Do) is connected to BiSW pin. When the analog switch is OFF, BiSW pin is set to high-impedance state.

LE	Analog Switch
H (Changing the divide ratio of internal prescaler)	ON
L (Normal operationg mode)	OFF

When an analog switch is inserted between LP1 and LP2, faster lock up times is achieved to reduce LPF time constant during PLL channal switching.



■ ABSOLUTE MAXIMUM RATINGS (See WARNING)

Parameter	Symbol	Rat	Unit		
Farameter	Symbol	Min. Max.			
Power cupply veltage	Vcc	-0.5	+7.0	V	
Power supply voltage	VP	Vcc	+10.0	V	
Output voltage	Vouт	-0.5	Vcc +0.5	V	
Open-drain voltage	Voop	-0.5	+8.0	V	
Output current	Іоит	-10	+10	mA	
Storage temperature	Tstg	– 55	+125	°C	

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Onit
Power aunaly voltage	Vcc	2.7	3.0	5.5	V
Power supply voltage	VP	Vcc	_	8.0	V
Input voltage	VIN	GND	_	Vcc	V
Operating temperature	Та	-40	_	+85	°C

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

> Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

> No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

HANDLING PRECAUTIONS

- This device should be transported and stored in anti-static containers.
- This is static-sensitive device; take proper anti-ESD precautions. Ensure that personnel and equipment are properly grounded. Cover workbenches with grounded conductive mats.
- Always turn the power supply off before inserting or removing the device from its socket.
- Protect leads with a conductive sheet when handing or transporting PC boards with devices.

■ ELECTRICAL CHARACTERINSTICS

 $(Vcc = 2.7 \text{ V to } 5.5 \text{ V}, Ta = -40^{\circ}\text{C to } +85^{\circ}\text{C})$

Parameter		Cumbal		Unit		
		Symbol	Min.	Тур.	Max.	Onit
Power supply current*1		Icc	_	7.0	_	mA
Operating frequency	fin*2	fin	10	_	1100	MHz
Operating frequency	OSCIN	fosc	_	12	20	MHz
	fin-1*3	V _{fin1}	-4	_	6	dBm
Input sensitivity	fin-2*4	V _{fin2}	-10	_	6	dBm
	OSCIN	Vosc	0.5	_	_	V _{p-p}
High-level input voltage	Except fin and	VIH	Vcc×0.7	_	_	V
Low-level input voltage	OSCin	VIL	_	_	Vcc×0.3	V
High-level input current	Data, clock	Іін	_	1.0	_	μΑ
Low-level input current	Data, Clock	lıL	_	-1.0	_	μΑ
Input current	OSCIN	losc	_	±50	_	μΑ
Imput current	LE, FC	ILE	_	-60	_	μΑ
High-level output voltage	Except Do	VoH*5	2.2	_	_	V
Low-level output voltage	and OSCоит	Vol	_	_	0.4	V
N-channel open drain cutoff current	Do, φP*6	loff	_	_	1.1	μΑ
Output ourrant	Except Do	Іон	-1.0	_	_	mA
Output current	and OSCout	lol	1.0	_	_	mA
Analog switch on resistance	е	Ron	_	25	_	Ω

^{*1:} fin =1.1 GHz, OSC_{IN}=12 MHz, Vcc=3V. Inputs are grounded and outputs are open.

^{*2:} AC coupling. Minimum operating frequency is measured when a capacitor 1000pF.

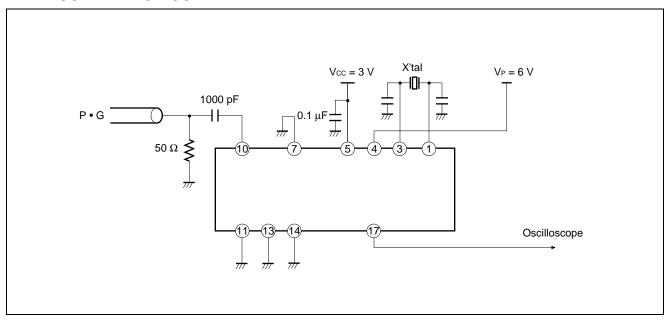
^{*3:} Vcc=4.0 to 5.5V, 50 (Ω)

^{*4:} Vcc=2.7 to 4.0V, 50 (Ω)

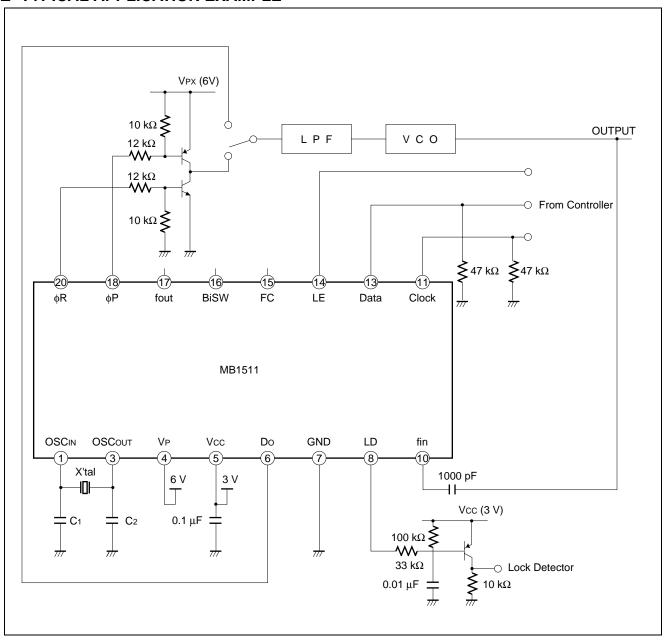
^{*5:} Vcc=3V

^{*6:} VP=Vcc to 8V, VooP=GND to 8V

■ MEASURMENT CIRCUIT



■ TYPICAL APPLICATION EXAMPLE



 $V_{PX},\,V_{P}$: 8 V max.

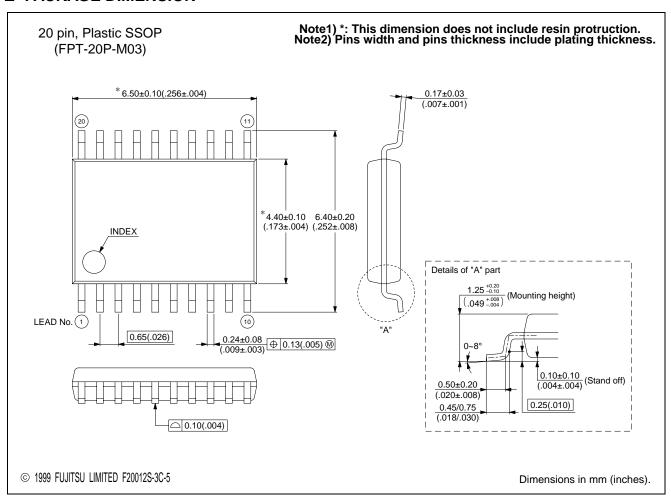
 C_1, C_2 : Depends on crystal oscillator LE, FC: With internal pull up resistor

φP : Open drain output

■ ORDERING INFORMATION

Part number	Package	Remarks
MB1511PFV	20-pin plastic SSOP (FPT-20P-M03)	

■ PACKAGE DIMENSION



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